

**- Product Change Notification -
- Samsung DDR3 1Gb G die based Solution-**

Date: Dec.18, 2015

No:PCN151218002

Dear Valued Customer:

This notification is to inform the change of DRAM migration into our DDR3 products.

Please find out our Apacer Technology Inc. PCN:

Subject	Samsung DDR3 1Gb x8 G die DRAM IC	
Of Change		
Products Affected	Following is the list of the relative part numbers which is built with Samsung DDR3 1Gb x8 G die DRAM IC	
Reason Of Change	Samsung has decided to announce the "Die Revision" of 1GDDR38 products in order to streamline the product portfolio and to concentrate on more advanced products.	
Dram P/N Identification	OLD	NEW
	Samsung DDR3 1Gb x8 G die DRAM IC 35nm	Samsung DDR3 1Gb x8 die DRAM IC 25nm
Time Schedule	The date for alternative :Now The due date for Last-Time Buy: May.31,2016 Last-Time Shipment(LTS) : Nov.30.2016	

Please contact your account sales if you have any question on this PCN. Thank you for your attention and cooperation

Sincerely yours,
Apacer Technology Inc.

**DRAM Module with Samsung DDR3 1Gb x8 G die DRAM IC
Affected Apacer P/N**

78.01GC3.400	75.073DP.G000C	78.A2GD7.4030C
78.A1GC3.401	75.073C1.G140C	78.02GD5.4000C
78.A1GC8.403	75.073C7.G090C	
78.A2GC3.401	78.02GCA.4010C	
76.0164G.C1N0C	78.02GC3.4000C	
75.073DF.G000C	78.A2GC6.4010C	
78.A1GC6.4010C	78.01GKQ.4000C	
76.0372G.C4E0C	78.01GC8.4020C	
78.02GD7.4000C	76.0151G.C6H0C	
78.01GJT.4000C	76.0183G.C6H0C	
75.073E0.G000C	76.A183G.C6S0C	
78.01GC6.4000C	78.A1GJT.40F0C	
76.0153G.C6D0C	76.0183G.C6T0C	
78.01GFS.4010C	75.073C6.G070C	
78.02GC6.4000C	78.02GDS.4010C	